TAYCHIPST

SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

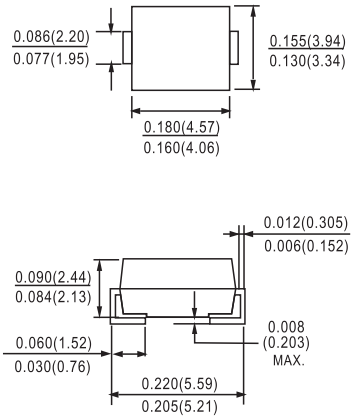
SKL13B

30V 1.0A

FEATURES

- For surface mounted application
- Metal silicon junction, majority carrier conduction
- Low forward voltage drop
- Easy pick and place
- High surge current capability
- Plastic material used carries Underwriters Laboratory Classification 94V-0
- Epitaxial construction
- High temperature soldering: 260°C / 10 seconds at terminals

DO-214AA(SMB)



Dimensions in inches and (millimeters)

MECHANICAL DATA

Cases: Molded plastic
Terminals: Matte tin plating
Polarity: Indicated by cathode band
Packaging: 16mm tape per EIA STD RS-481
Weight: 0.093 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%

Type Number	Symbol	SKL13B	Unit
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	30	V
Maximum RMS Voltage	V_{RMS}	21	V
Maximum DC Blocking Voltage	V_{DC}	30	V
Maximum Average Forward Rectified Current See Fig. 1	$I_{(AV)}$	1.0	A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	50	A
Maximum Instantaneous Forward Voltage (Note 1) @ 1.0A	V_F	0.39	V
Maximum DC Reverse Current @ T_A =25°C	I_R	0.2	mA
at Rated DC Blocking Voltage @ T_A=100°C		50	mA
Maximum Thermal Resistance (Note 2)	$R_{\theta JL}$ $R_{\theta JA}$	30 85	°C/W
Operating Temperature Range	T_J	-55 to +125	°C
Storage Temperature Range	T_{STG}	-55 to + 150	°C

Notes: 1. Pulse Test with PW=300 usec, 1% Duty Cycle.
2. Measured on P.C. Board with 0.4" x 0.4" (10 x 10mm) Copper Pad Areas.

RATINGS AND CHARACTERISTIC CURVES SKL13B

FIG.1- MAXIMUM FORWARD CURRENT DERATING CURVE

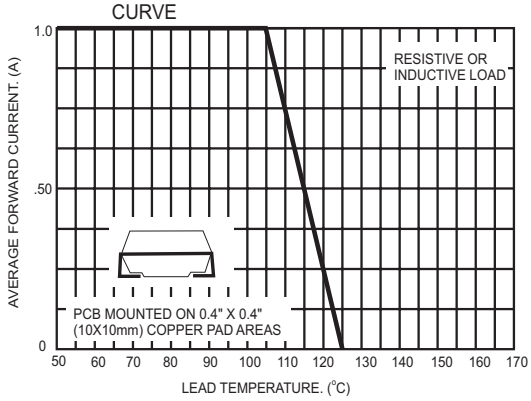


FIG.2- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

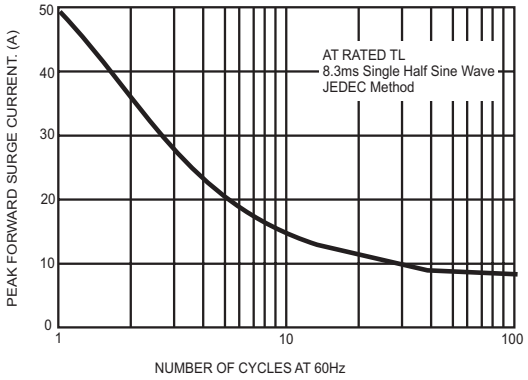


FIG.3- TYPICAL FORWARD CHARACTERISTICS

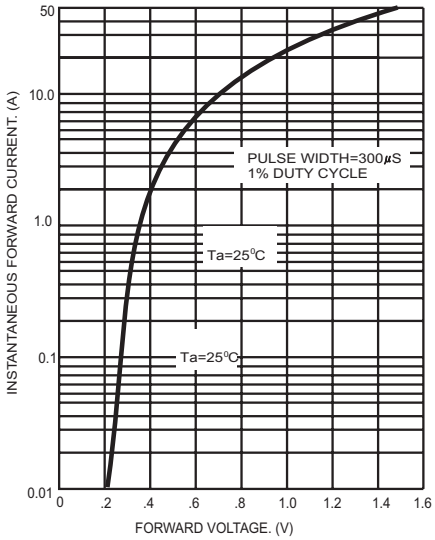


FIG.4- TYPICAL REVERSE CHARACTERISTICS

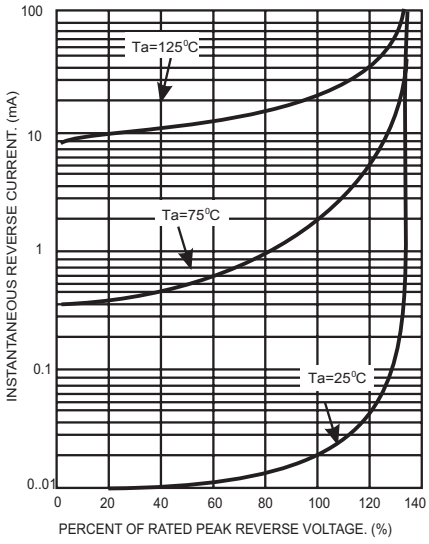


FIG.5- TYPICAL JUNCTION CAPACITANCE